

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	2	"20040155244"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/17 15:12
S2	2	("6207586").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/05/17 15:16
S3	11	@ad<="20040114" and 'TFT' and 'monocrystalline silicon' and 'thermal oxide' same 'cvd' with 'oxide'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/06 08:14
S4	9	@ad<="20040114" and 'TFT' and 'monocrystalline silicon' and 'gate insulating' with 'thermal oxide'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/17 15:37
S5	198	@ad<="20040114" and 'monocrystalline silicon' and 'thermal oxide' same 'cvd'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/17 15:31
S6	4	@ad<="20040114" and 'TFT' and 'monocrystalline silicon' and 'gate' with 'thermal oxide' with 'cvd'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/17 15:38
S7	22	@ad<="20040114" and 'TFT' and 'monocrystalline silicon' and 'gate insulating' and 'thermal oxide' and 'cvd'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/17 15:52
S10	116	@ad<="20040114" and 'gate insulating' same 'thermal oxide' with 'cvd'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/17 15:52
S11	4	@ad<="20040114" and 'tft;' and 'monocrystalline silicon' with 'thermal oxide'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/17 15:54
S12	70	@ad<="20040114" and 'monocrystalline silicon' with 'thermal oxide'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/17 15:54

EAST Search History

S13	34	@ad<="20040114" and 'TFT' and 'monocrystalline silicon' and 'thermal oxide'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/17 16:05
S14	112	@ad<="20040114" and 'TFT' and 'monocrystalline silicon' and 'oxidized'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/03 07:58
S15	1	"20030116719".PN.	US-PGPUB	OR	ON	2005/05/17 16:05
S16	1	"20030085397".PN.	US-PGPUB	OR	ON	2005/05/17 16:05
S17	138	@ad<="20040114" and 'LCD' and 'monocrystalline silicon' and 'oxide' same 'nitride'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/18 08:40
S18	15	@ad<="20040114" and 'electro-optical' and 'monocrystalline silicon' and 'thermal oxide'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/18 08:40
S19	9	@ad<="20040114" and 'LCD' and 'monocrystalline silicon' and 'thermal oxide'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/18 08:40
S20	131	@ad<="20040114" and 'LCD' and 'monocrystalline silicon' and 'oxide' with 'nitride'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/18 08:40
S22	1	'wo 200011709'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/18 09:05
S23	1	"5432625".PN.	USPAT; USOCR	OR	ON	2005/05/18 10:28
S24	3	@ad<="20040114" and 'TFT' and 'monocrystal' with 'silicon' and 'insulating' with 'thermal oxide'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/02 14:25
S25	102	@ad<="20040114" and 'TFT' and 'single' with 'crystal' with 'silicon' and 'insulating' with 'thermal oxide'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/18 11:23
S26	80	@ad<="20040114" and 'TFT' and 'single' with 'crystal' with 'silicon' and 'insulating' with 'thermal oxide' and 'oxide' with 'cvd'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/02 15:58

EAST Search History

S27	3	("6011275").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/05/18 11:52
S28	9251	@ad<="20040114" and (257/59). ccls. or (257/347).ccls. or (257/64). ccls. or (257/65).ccls. or (257/66). ccls. or (257/67).ccls. or (257/72). ccls. or (257/E21.413).ccls. or (257/E21.703).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/18 11:55
S29	704	@ad<="20040114".and (257/57). ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/18 12:04
S30	1155	@ad<="20040114" and (257/79). ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/18 12:04
S31	81	@ad<="20040114" and 'TFT' and 'single' with 'crystal' with 'silicon' and 'insulating' with 'thermal oxide' and 'oxide' with 'cvd'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/02 14:26
S32	3	@ad<="20040114" and 'TFT' and 'monocrystal' with 'silicon' and 'insulating' with 'thermal oxide'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/02 16:02
S33	36	@ad<="20040114" and 'TFT' and 'single' with 'crystal' with 'silicon' and 'insulating' with 'thermal oxide' and 'oxide' with 'cvd' and 'LDD'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/06 08:20
S34	9	("6077731").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/02 14:58
S45	110	@ad<="20040114" and 'single crystal' with 'silicon' same 'mono'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/02 15:55
S46	81	@ad<="20040114" and 'TFT' and 'single' with 'crystal' with 'silicon' and 'insulating' with 'thermal oxide' and 'oxide' with 'cvd'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/02 15:58

EAST Search History

S47	855	@ad<="20040114" and 'TFT' and 'monocrystalline'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/02 16:02
S48	61	@ad<="20040114" and 'TFT' and 'monocrystalline' and 'gate' with 'thermal' with 'cvd'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/02 16:05
S49	7	@ad<="20040114" and 'TFT' and 'monocrystalline' and 'gate' with 'thermal' with 'cvd' and 'ldd'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/02 16:05
S50	38	@ad<="20040114" and 'TFT' and 'monocrystalline' and 'thermal' with 'cvd' and 'ldd'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/02 16:05
S51	0	@ad<="20040114" and 'TFT' and 'insulating gate' with 'capacitor line'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/03 07:59
S52	183	@ad<="20040114" and 'TFT' and 'gate insulating' same 'capacitor line'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/03 08:00
S53	136	@ad<="20040114" and 'TFT' and 'gate insulating' with 'capacitor line'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/03 08:00
S54	31	@ad<="20040114" and 'TFT' with 'gate insulating' with 'capacitor line'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/03 08:00
S55	183	@ad<="20040114" and 'TFT' and ('monocrystalline' or 'monocrystal' or 'crystallinity') with 'silicon' and 'thermal oxide'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/05 15:57
S56	71	@ad<="20040114" and 'TFT' and ('monocrystalline' or 'monocrystal' or 'crystallinity') with 'silicon' and 'thermal oxide' same 'cvd' same 'oxide'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/11 09:58
S57	1	@ad<="20040114" and 'TFT' same 'monocrystalline' with 'silicon' and 'thermal oxide' same 'cvd' same 'oxide'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/05 16:00

EAST Search History

S58	8	@ad<="20040114" and 'TFT' same 'monocrystalline' with 'silicon' and 'thermal oxide'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/05 16:02
S59	200	@ad<="20040114" and 'TFT' same 'monocrystalline' with 'silicon'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/05 16:02
S60	128	@ad<="20040114" and 'TFT' with 'monocrystalline' with 'silicon'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/05 16:02
S61	111	@ad<="20040114" and 'TFT' with 'monocrystalline silicon'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/05 16:07
S62	37	@ad<="20040114" and 'TFT' and 'monocrystalline silicon' same 'channel' and 'LDD'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/05 16:22
S63	8	@ad<="20040114" and 'TFT' and 'monocrystalline silicon' same 'active layer'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/06 08:13
S64	0	@ad<="20040114" and 'TFT' same 'monocrystalline semiconductor' with 'active layer' same 'thermal oxide' same 'cvd' with 'oxide'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/06 08:13
S65	0	@ad<="20040114" and 'TFT' same 'monocrystalline' with 'active layer' same 'thermal oxide' same 'cvd' with 'oxide'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/06 08:14
S66	0	@ad<="20040114" and 'TFT' same 'monocrystalline' with 'active' same 'thermal oxide' same 'cvd' with 'oxide'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/06 08:14
S67	0	@ad<="20040114" and 'TFT' and 'monocrystalline' with 'active' same 'thermal oxide' same 'cvd' with 'oxide'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/06 08:14
S68	11	@ad<="20040114" and 'TFT' and 'monocrystalline silicon' and 'thermal oxide' same 'cvd' with 'oxide'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/06 08:14

EAST Search History

S69	0	@ad<="20040114" and 'TFT' and 'monocrystalline' with 'active' and 'thermal oxide' same 'cvd' with 'oxide'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/06 08:14
S70	8	@ad<="20040114" and 'TFT' and 'mono' with 'crystal' with 'silicon' and ('insulating' or 'dielectric') with 'thermal oxide' and ('oxide' or 'nitride') with 'cvd' and 'LDL'	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/06 08:21
S71	67	@ad<="20040114" and ("TFT" or "thin film transistor") and (monocrystal\$4 or "crystallinity") with silicon and "thermal oxide" same ("cvd" with oxide)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/04/11 10:01
S72	78	@ad<="20040114" and crystal with silicon same mono and shield\$4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/08 14:45

EAST Search History

S73	192	("3389024" "3783049" "3890632" "4059461" "4068020" "4132571" "4174217" "4226898" "4231809" "4271422" "4277884" "4300989" "4309224" "4330363" "4331709" "4379020" "4409724" "4466073" "4472458" "4481121" "4534820" "4544418" "4546376" "4597160" "4634473" "4735824" "4755481" "4911781" "4959247" "4959700" "4996077" "4996523" "5043224" "5075259" "5089441" "5112764" "5145808" "5147826" "5173446" "5200630" "5221423" "5225355" "5244836" "5254480" "5262350" "5262654" "5275851" "5278093" "5289030" "5296405" "5298075" "5308998" "5313075" "5352291" "5354697" "5358907" "5366926" "5387530" "5403772" "5424230" "5426064" "5470763" "5480811" "5481121" "5488000" "5492843" "5501989" "5504019" "5508207" "5508533" "5529937" "5530266" "5531182" "5534716" "5543352" "5543636" "5550070" "5563426" "5569610" "5569936" "5580792" "5580815" "5585291" "5589694" "5591988" "5595923" "5595944" "5604360" "5605846" "5606179" "5608232" "5612250" "5614426" "5614733" "5616506" "5619044" "5620910" "5621224" "5621244" "5624851" "5637515" "5639698" "5643826" "5646424" "5654203" "5656825" "5661311" "5663077" "5677549" "5684317" "5684365" "5686328" "5693541" "5693959" "5696003" "5696386" "5696388" "5700333" "5705829" "5712191" "5717224" "5728259" "5734179" "5744822" "5744824").PN. OR ("5756364" "5763899" "5766977" "5773327" "5773846" "5773847" "5782665" "5786796" "5795795" "5808321" "5811327" "5818076" "5821138" "5821560" "5824574" "5828429" "5838508" "5843225" "5846857" "5849611" "5882960" "5888858" "5895933" "5899547" "5922125" "5929464" "5929527" "5933205" "5940732" "5949107" "5953597" "5962869" "5963278" "5985740" "5990491" "5990542" "6005648" "6011275" "6011277" "6013929" "6031249" "6048758" "6063654" "6077731" "6083801" "6093934" "6100562" "6121683" "6140165" "6147667" "6175348" "6180439" "6207969" "6278132" "6331718" "RE28385"	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/08 15:29
12/6/06 9:08:04 AM	"RE28386") PN. OR ("6528358")				Page 7	
C:\Documents and Settings\steve10\My Documents\EAST\Workspaces\Thin Film Transistor\10756409 Seiko TFT w_ thermal and CVD oxi	URPN.					

EAST Search History

S74	40	("5353133" "5488236" "5574475" "5648792").PN. OR ("5808595").URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/08/08 15:43
S75	2	("6,433,767").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/08/08 15:43
S76	2	("6818921").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/12/05 10:02
S77	4	"20030207545"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/12/05 09:57
S78	2	("6127702").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/12/05 10:42
S79	2	("6,583,440").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/12/05 10:02